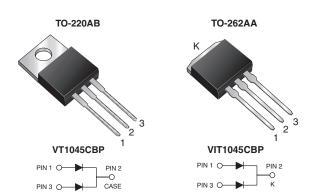
# VT1045CBP, VIT1045CBP

Vishay General Semiconductor

## TMBS<sup>®</sup> (Trench MOS Barrier Schottky) Rectifier for PV Solar Cell Bypass Protection

Ultra Low  $V_F = 0.34$  V at  $I_F = 2.5$  A



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PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
V <sub>RRM</sub>	45 V				
I <sub>FSM</sub>	100 A				
$V_F$ at $I_F = 5.0$ A	0.41 V				
T <sub>OP</sub> max. (AC mode)	150 °C				
T <sub>J</sub> max. (DC forward current)	200 °C				
Package	TO-220AB, TO-262AA				
Circuit configurations	Common cathode				

### **FEATURES**

- Trench MOS Schottky technology
- · Low forward voltage drop, low power losses
- High efficiency operation
- Solder dip 275 °C max. 10 s, per JESD 22-B106
- T<sub>.1</sub> 200 °C max. in solar bypass mode application
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

### TYPICAL APPLICATIONS

For use in solar cell junction box as a bypass diode for protection, using DC forward current without reverse bias.

### **MECHANICAL DATA**

Case: TO-220AB, TO-262AA Molding compound meets UL 94 V-0 flammability rating Base P/N-M3 - halogen-free, RoHS-compliant, and commercial grade

Terminals: matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

M3 suffix meets JESD 201 class 1A whisker test

#### Polarity: as marked

Mounting Torque: 10 in-lbs maximum

<b>MAXIMUM RATINGS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		SYMBOL	VT1045CBP	VIT1045CBP	UNIT	
Maximum repetitive peak reverse voltage		V <sub>RRM</sub>	45		V	
Maximum average forward rectified current (fig. 1)	per device	I (1)	10		А	
	per diode	I <sub>F(AV)</sub> <sup>(1)</sup>	5.0			
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode		I <sub>FSM</sub>	100		А	
Operating junction and storage temperature range (AC mode)		T <sub>OP</sub> , T <sub>STG</sub>	-40 to	+150	°C	
Junction temperature in DC forward current without reverse bias, $t \leq 1 \ h$		T <sub>J</sub> <sup>(2)</sup>	≤2	00	°C	

Notes

<sup>(1)</sup> With heatsink

<sup>(2)</sup> Meets the requirements of IEC 61215 ed. 2 bypass diode thermal test

<b>ELECTRICAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER	TEST CONDITIONS		SYMBOL	TYP.	MAX.	UNIT
Instantaneous forward voltage per diode	I <sub>F</sub> = 2.5 A	T 05 %0		0.44	-	
	$T_{\rm F} = 2.3 \text{ A}$ $T_{\rm A} = 25 \text{ °C}$	V <sub>F</sub> <sup>(1)</sup>	0.49	0.58	v	
	I <sub>F</sub> = 2.5 A	T <sub>A</sub> = 125 °C	VF	0.34	-	
	I <sub>F</sub> = 5.0 A			0.41	0.50	
Reverse current per diode	$V_{R} = 45 V = \frac{T_{A} = 25 °C}{T_{A} = 125 °C}$	1 (2)	-	500	μA	
		T <sub>A</sub> = 125 °C	I <sub>R</sub> <sup>(2)</sup>	5	15	mA

#### Notes

<sup>(1)</sup> Pulse test: 300 µs pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

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<b>THERMAL CHARACTERISTICS</b> ( $T_A = 25 \text{ °C}$ unless otherwise noted)						
PARAMETER		SYMBOL	VT1045CBP VIT1045CBP		UNIT	
Typical thermal resistance	per diode	$R_{ ext{ heta}JC}$	3.5		°C/W	
	per device		2.5			

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AB	VT1045CBP-M3/4W	1.87	4W	50/tube	Tube		
TO-262AA	VIT1045CBP-M3/4W	1.45	4W	50/tube	Tube		

## **RATINGS AND CHARACTERISTICS CURVES** ( $T_A = 25$ °C unless otherwise noted)

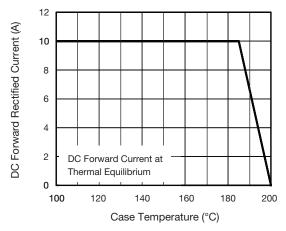


Fig. 1 - Maximum Forward Current Derating Curve

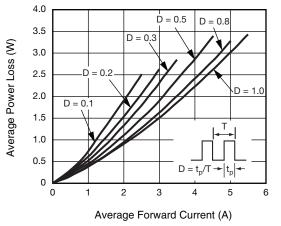


Fig. 2 - Forward Power Loss Characteristics Per Diode

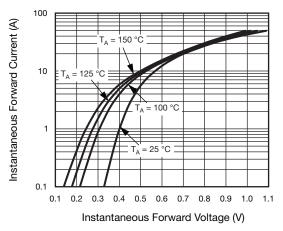


Fig. 3 - Typical Instantaneous Forward Characteristics Per Diode

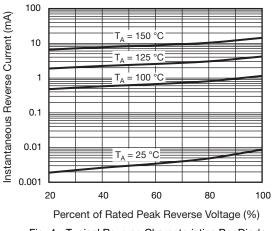


Fig. 4 - Typical Reverse Characteristics Per Diode



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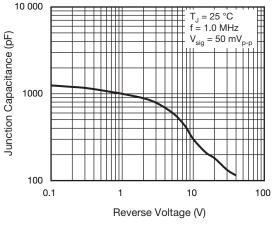


Fig. 5 - Typical Junction Capacitance Per Diode

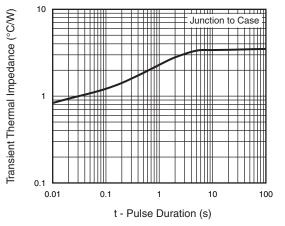
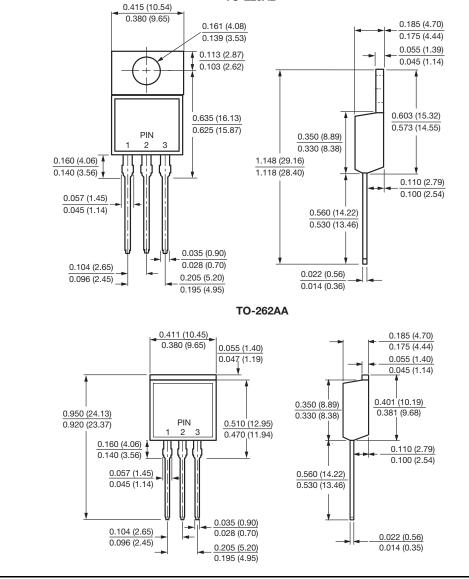


Fig. 6 - Typical Transient Thermal Impedance Per Diode





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